**New Product** 

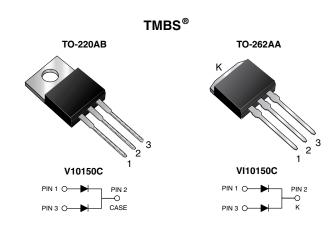


## V10150C, VI10150C

Vishay General Semiconductor

## **Dual High-Voltage Trench MOS Barrier Schottky Rectifier**

Ultra Low  $V_F = 0.63$  V at  $I_F = 3$  A



| PRIMARY CHARACTERISTICS                |           |  |  |  |  |
|--|-----------|--|--|--|--|
| I <sub>F(AV)</sub>                     | 2 x 5.0 A |  |  |  |  |
| V <sub>RRM</sub>                       | 150 V     |  |  |  |  |
| I <sub>FSM</sub>                       | 60 A      |  |  |  |  |
| V <sub>F</sub> at I <sub>F</sub> = 5 A | 0.69 V    |  |  |  |  |
| T <sub>J</sub> max.                    | 150 °C    |  |  |  |  |

#### **FEATURES**

- Trench MOS Schottky technology
- Low forward voltage drop, low power losses
- High efficiency operation
- Solder dip 275 °C max. 10 s, per JESD 22-B106
- AEC-Q101 qualified
- Compliant to RoHS Directive 2002/95/EC and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21 definition

#### **TYPICAL APPLICATIONS**

For use in high frequency DC/DC converters, switching power supplies, freewheeling diodes, OR-ing diode, and reverse battery protection.

#### **MECHANICAL DATA**

Case: TO-220AB and TO-262AA

Molding compound meets UL 94 V-0 flammability rating

Base P/N-M3 - halogen-free, RoHS compliant, and commercial grade

Base P/NHM3 - halogen-free, RoHS compliant, and AEC-Q101 qualified

Terminals: Matte tin plated leads. solderable per J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test. HM3 suffix meets JESD 201 class 2 whisker test

#### Polarity: As marked

Mounting Torque: 10 in-lbs maximum

| <b>MAXIMUM RATINGS</b> ( $T_A = 25 \text{ °C}$ unless otherwise noted)                          |            |                                   |         |          |      |  |
|---|------------|-----------------------------------|---------|----------|------|--|
| PARAMETER   |            | SYMBOL                            | V10150C | VI10150C | UNIT |  |
| Maximum repetitive peak reverse voltage   |            | V <sub>RRM</sub>                  | 150     |          | V    |  |
| Maximum average forward rectified current (fig. 1)  | per device | 1                                 | 10      |          | A    |  |
|   | per diode  | I <sub>F(AV)</sub>                | 5.0     |          |      |  |
| Peak forward surge current 8.3 ms single half sine-wave<br>superimposed on rated load per diode |            | I <sub>FSM</sub>                  | 60      |          | А    |  |
| Voltage rate of change (rated V <sub>R</sub> )  |            | dV/dt                             | 10 000  |          | V/µs |  |
| Operating junction and storage temperature range  |            | T <sub>J</sub> , T <sub>STG</sub> | - 55 to | + 150    | °C   |  |

RoHS COMPLIANT HALOGEN FREE

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| <b>ELECTRICAL CHARACTERISTICS</b> ( $T_A = 25 \text{ °C}$ unless otherwise noted) |                        |                           |                               |      |      |      |  |
|---|------------------------|---------------------------|-------------------------------|------|------|------|--|
| PARAMETER   | TEST CONDITIONS        |                           | SYMBOL                        | TYP. | MAX. | UNIT |  |
| Instantaneous forward voltage per diode   | I <sub>F</sub> = 3 A   | T <sub>A</sub> = 25 °C    | - V <sub>F</sub> (1)          | 0.82 | -    | V    |  |
|   | I <sub>F</sub> = 5 A   |                           |                               | 0.99 | 1.41 |      |  |
|   | I <sub>F</sub> = 3 A   | - T <sub>A</sub> = 125 °C |                               | 0.63 | -    |      |  |
|   | I <sub>F</sub> = 5 A   |                           |                               | 0.69 | 0.75 |      |  |
| Reverse current per diode   | V <sub>R</sub> = 100 V | T <sub>A</sub> = 25 °C    | I <sub>R</sub> <sup>(2)</sup> | 0.5  | -    | μA   |  |
|   |                        | T <sub>A</sub> = 125 °C   |                               | 0.5  | -    | mA   |  |
|   | V <sub>P</sub> = 150 V | T <sub>A</sub> = 25 °C    |                               | _    | 100  | μA   |  |
|   |                        | T <sub>A</sub> = 125 °C   |                               | 1.0  | 10   | mA   |  |

#### Notes

<sup>(1)</sup> Pulse test: 300 µs pulse width, 1 % duty cycle

<sup>(2)</sup> Pulse test: Pulse width  $\leq$  40 ms

| <b>THERMAL CHARACTERISTICS</b> ( $T_A = 25 \text{ °C}$ unless otherwise noted) |                       |                    |  |      |  |
|--|-----------------------|--------------------|--|------|--|
| PARAMETER  | SYMBOL                | L V10150C VI10150C |  | UNIT |  |
| Typical thermal resistance per diode   | $R_{	extsf{	heta}JC}$ | 4.0                |  | °C/W |  |

| ORDERING INFORMATION (Example) |                               |                 |              |               |               |  |  |
|--------------------------------|-------------------------------|-----------------|--------------|---------------|---------------|--|--|
| PACKAGE                        | PREFERRED P/N                 | UNIT WEIGHT (g) | PACKAGE CODE | BASE QUANTITY | DELIVERY MODE |  |  |
| TO-220AB                       | V10150C-M3/4W                 | 1.87            | 4W           | 50/tube       | Tube          |  |  |
| TO-262AA                       | VI10150C-M3/4W                | 1.45            | 4W           | 50/tube       | Tube          |  |  |
| TO-220AB                       | V10150CHM3/4W (1)             | 1.87            | 4W           | 50/tube       | Tube          |  |  |
| TO-262AA                       | VI10150CHM3/4W <sup>(1)</sup> | 1.45            | 4W           | 50/tube       | Tube          |  |  |

Note

(1) AEC-Q101 qualified

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**New Product** 



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#### **RATINGS AND CHARACTERISTICS CURVES**

(T<sub>A</sub> = 25 °C unless otherwise noted)

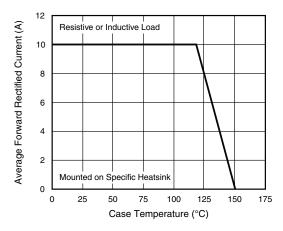


Fig. 1 - Maximum Forward Current Derating Curve

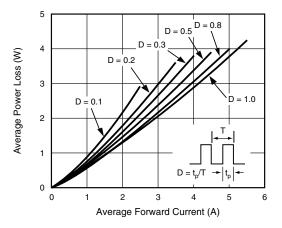


Fig. 2 - Forward Power Loss Characteristics Per Diode

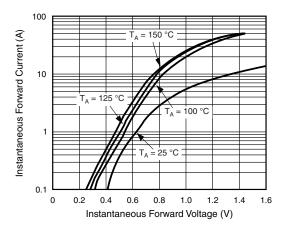


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

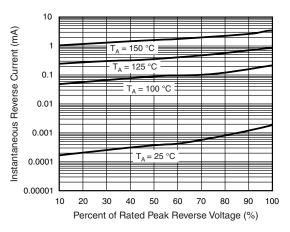


Fig. 4 - Typical Reverse Characteristics Per Diode

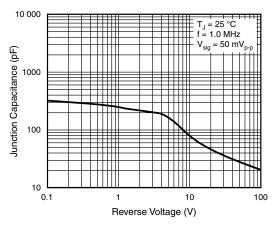
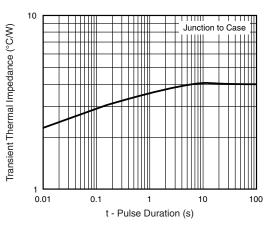
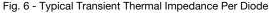


Fig. 5 - Typical Junction Capacitance Per Diode





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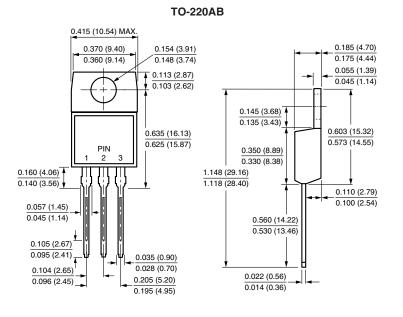
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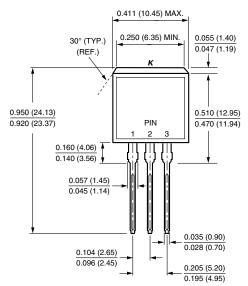
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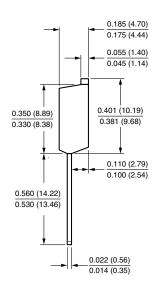
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#### PACKAGE OUTLINE DIMENSIONS in inches (millimeters)



TO-262AA







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